

TOSHIBA PHOTOCOUPLER GaAs IRED &amp; PHOTO-TRIAC

**T L P 3 5 0 7**

TRIAC DRIVER

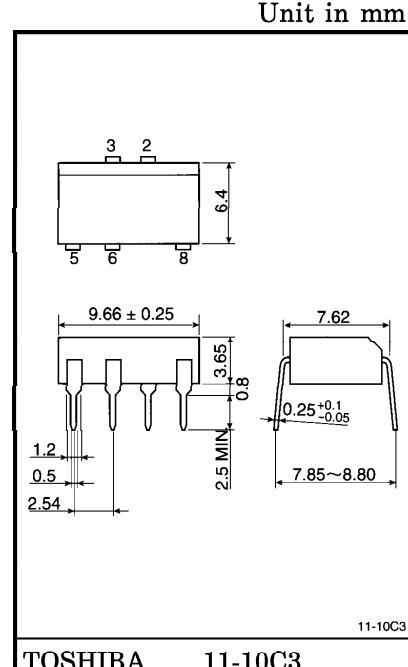
PROGRAMMABLE CONTROLLERS

AC-OUTPUT MODULE

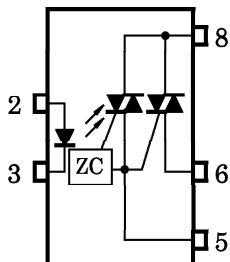
SOLID STATE RELAY

The TOSHIBA TLP3507 consists of a zero voltage crossing turn-on photo-triac optically coupled to a gallium arsenide infrared emitting diode in a 8 lead plastic DIP package.

- Peak Off-State Voltage : 600V (MIN.)
- Trigger LED Current : 10mA (MAX.)
- On-State Current : 0.5A<sub>rms</sub> (MAX.)
- Isolation Voltage : 2500V<sub>rms</sub> (MIN.)
- Zero Crossing Function
- UL Recognized : UL1577, File No. E67349



## PIN CONFIGURATIONS (TOP VIEW)



- 2 : ANODE
- 3 : CATHODE
- 5 : TRIAC GATE
- 6 : TRIAC T1
- 8 : TRIAC T2

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MAXIMUM RATINGS ( $T_a = 25^\circ\text{C}$ )

CHARACTERISTIC		SYMBOL	RATING	UNIT
LED	Forward Current	$I_F$	50	mA
	Forward Current Derating ( $T_a \geq 53^\circ\text{C}$ )	$\Delta I_F / ^\circ\text{C}$	-0.7	mA / $^\circ\text{C}$
	Peak Forward Current (100 $\mu\text{s}$ pulse, 100pps)	$I_{FP}$	1	A
	Reverse Voltage	$V_R$	5	V
	Junction Temperature	$T_j$	125	$^\circ\text{C}$
DETECTOR	Off-State Output Terminal Voltage	$V_{DRM}$	600	V
	On-State RMS Current	$I_T (\text{RMS})$	0.5	A
			0.35	
	On-State Current Derating ( $T_a \geq 40^\circ\text{C}$ )	$\Delta I_T / ^\circ\text{C}$	-7.2	mA / $^\circ\text{C}$
	Peak Current from Snubber Circuit (100 $\mu\text{s}$ pulse, 120pps)	$I_{SP}$	2	A
	Peak Nonrepetitive Surge Current (50Hz, Peak)	$I_{TSM}$	5	A
	Junction Temperature	$T_j$	110	$^\circ\text{C}$
Storage Temperature Range		$T_{stg}$	-40~125	$^\circ\text{C}$
Operating Temperature Range		$T_{opr}$	-20~80	$^\circ\text{C}$
Lead Soldering Temperature (10s)		$T_{sol}$	260	$^\circ\text{C}$
Isolation Voltage (AC, 1 min., R.H. $\leq 60\%$ ) (Note)		$BVS$	2500	$V_{rms}$

(Note) Device considereded a two-terminal device : Pins 2 and 3 shorted together, and pins 5, 6 and 8 shorted together.

## RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	$V_{AC}$	—	—	240	$V_{ac}$
Forward Current	$I_F$	15	20	25	mA
Peak Current from Snubber Circuit	$I_{SP}$	—	—	1	A
Operating Temperature	$T_{opr}$	-20	—	80	$^\circ\text{C}$

INDIVIDUAL ELECTRICAL CHARACTERISTICS ( $T_a = 25^\circ\text{C}$ )

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
LED	Forward Voltage	$V_F$	$I_F = 10\text{mA}$	1.0	1.15	1.3	V
	Reverse Current	$I_R$	$V_R = 5\text{V}$	—	—	10	$\mu\text{A}$
	Capacitance	$C_T$	$V = 0, f = 1\text{MHz}$	—	30	—	pF
DETECTOR	Peak Off-State Current	$I_{DRM}$	$V_{DRM} = 600\text{V}, T_a = 110^\circ\text{C}$	—	—	100	$\mu\text{A}$
	Peak On-State Voltage	$V_{TM}$	$I_{TM} = 0.75\text{A}$	—	—	3.0	V
	Holding Current	$I_H$	$R_L = 100\Omega$	—	—	25	mA
	Critical Rate of Rise of Off-State Voltage	$dv/dt$	$V_{in} = 240\text{V}_{\text{rms}}$ (Fig.1)	—	500	—	$\text{V}/\mu\text{s}$
	Critical Rate of Rise of Commutating Voltage	$dv/dt(c)$	$V_{in} = 240\text{V}_{\text{rms}}, I_T = 0.5\text{A}_{\text{rms}}$ (Fig.1)	—	5	—	$\text{V}/\mu\text{s}$

COUPLED ELECTRICAL CHARACTERISTICS ( $T_a = 25^\circ\text{C}$ )

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Trigger LED Current	$I_{FT}$	$V_T = 6\text{V}$	—	—	10	mA
Inhibit Voltage	$V_{IH}$	$I_F = \text{Rated } I_{FT}$	—	—	50	V
Leakage in Inhibited State	$I_{IH}$	$I_F = \text{Rated } I_{FT}$ $V_T = \text{Rated } V_{DRM}$	—	200	—	$\mu\text{A}$
Capacitance (Input to Output)	$C_S$	$V_S = 0, f = 1\text{MHz}$	—	1.5	—	pF
Isolation Resistance	$R_S$	$V_S = 500\text{V}, \text{R.H.} \leq 60\%$	$5 \times 10^{10}$	$10^{14}$	—	$\Omega$
Isolation Voltage	$BVS$	AC, 1 minute	2500	—	—	$\text{V}_{\text{rms}}$
		AC, 1 second, in oil	—	5000	—	
		DC, 1 minute, in oil	—	5000	—	$V_{dc}$

Fig.1 :  $dv/dt$  TEST CIRCUIT